

TO-252



Pin Definition:

1. Gate
2. Drain
3. Source

Key Parameter Performance

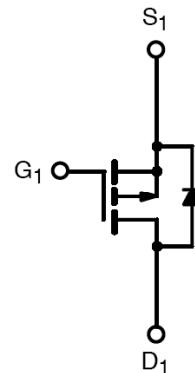
Parameter		Value	Unit
V_{DS}		-60	V
$R_{DS(on)}$ (max)	$V_{GS} = -10V$	180	$m\Omega$
	$V_{GS} = -4.5V$	220	
Q_g		8.2	nC

Ordering Information

Ordering code	Package	Packing
TSM7P06CP ROG	TO-252	2.5kpcs / 13" Reel

Note: Halogen-free according to IEC 61249-2-21 definition

Block Diagram



P-Channel MOSFET

Absolute Maximum Ratings ($T_C=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current <small>$T_C = 25^\circ C$</small>	I_D	-7	A
<small>$T_C = 100^\circ C$</small>		-4.4	A
Pulsed Drain Current <small>(Note 1)</small>	I_{DM}	-28	A
Single Pulse Avalanche Energy <small>(Note 2)</small>	E_{AS}	32	mJ
Single Pulse Avalanche Current <small>(Note 1)</small>	I_{AS}	-8	A
Power Dissipation @ $T_C = 25^\circ C$	P_D	15.6	W
Operating Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{STG}	-50 to +150	$^\circ C$

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Case	R_{eJC}	8	$^\circ C/W$
Thermal Resistance - Junction to Ambient	R_{eJA}	62	

Electrical Specifications ($T_C=25^\circ\text{C}$ unless otherwise noted)

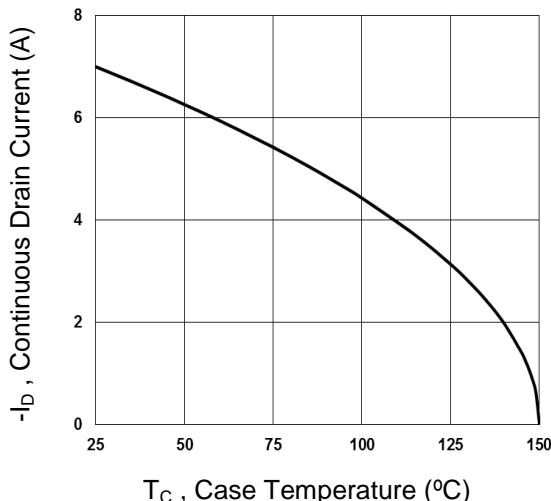
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}$, $I_D = -250\mu\text{A}$	BV_{DSS}	-60	--	--	V
Drain-Source On-State Resistance	$V_{GS} = -10\text{V}$, $I_D = -3\text{A}$	$R_{DS(\text{ON})}$	--	153	180	$\text{m}\Omega$
	$V_{GS} = -4.5\text{V}$, $I_D = -1.5\text{A}$		--	198	220	
Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250\mu\text{A}$	$V_{GS(\text{TH})}$	-1.2	-1.6	-2.5	V
Zero Gate Voltage Drain Current	$V_{DS} = -60\text{V}$, $V_{GS} = 0\text{V}$	I_{DSS}	--	--	-1	μA
	$V_{DS} = -48\text{V}$, $V_{GS} = 0\text{V}$, $T_C = 125^\circ\text{C}$		--	--	-10	
Gate Body Leakage	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Forward Transconductance ^(Note 3)	$V_{DS} = -10\text{V}$, $I_D = -2\text{A}$	g_{fs}	--	3	--	S
Dynamic						
Total Gate Charge ^(Note 3,4)	$V_{DS} = -30\text{V}$, $I_D = -3\text{A}$, $V_{GS} = -10\text{V}$	Q_g	--	8.2	--	nC
Gate-Source Charge ^(Note 3,4)		Q_{gs}	--	1.8	--	
Gate-Drain Charge ^(Note 3,4)		Q_{gd}	--	1.5	--	
Input Capacitance	$V_{DS} = -30\text{V}$, $V_{GS} = 0\text{V}$, $f = 1.0\text{MHz}$	C_{iss}	--	425	--	pF
Output Capacitance		C_{oss}	--	35	--	
Reverse Transfer Capacitance		C_{rss}	--	20	--	
Switching						
Turn-On Delay Time ^(Note 3,4)	$V_{DD} = -30\text{V}$, $I_D = -1\text{A}$, $R_{GEN} = 6\Omega$	$t_{d(on)}$	--	5.2	--	ns
Turn-On Rise Time ^(Note 3,4)		t_r	--	19	--	
Turn-Off Delay Time ^(Note 3,4)		$t_{d(off)}$	--	35	--	
Turn-Off Fall Time ^(Note 3,4)		t_f	--	10.6	--	
Source-Drain Diode Ratings and Characteristic						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	-7	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	-28	A
Diode-Source Forward Voltage	$V_{GS} = 0\text{V}$, $I_S = -1\text{A}$	V_{SD}	--	--	-1	V

Note:

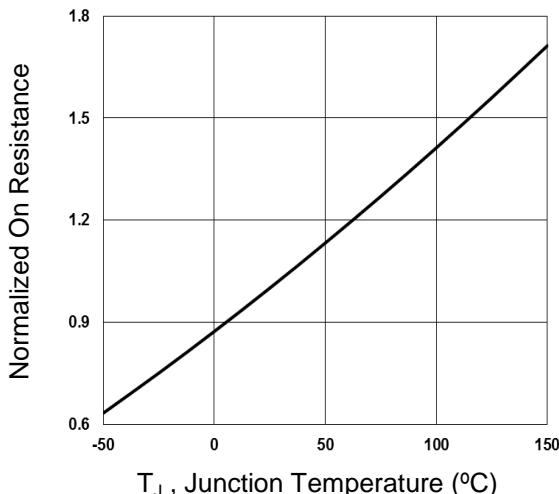
1. Pulse width limited by safe operating area
2. $L=1\text{mH}$, $I_{AS} = -8\text{A}$, $V_{DD} = -25\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
3. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
4. Switching time is essentially independent of operating temperature.

Electrical Characteristics Curve

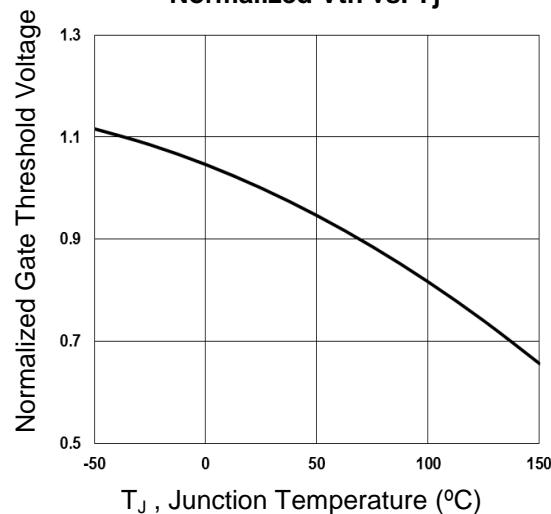
Continuous Drain Current vs. T_C



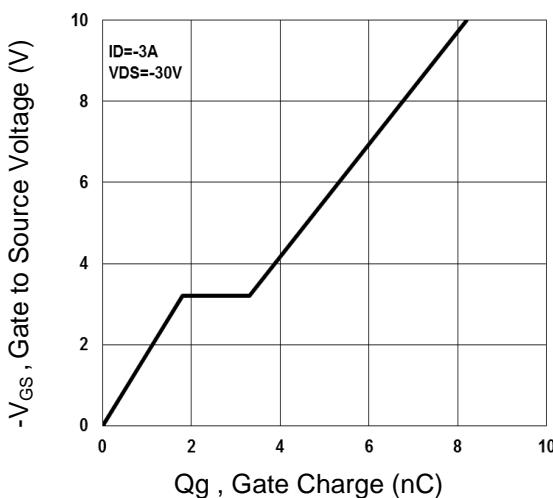
Normalized R_{d(on)} vs. T_j



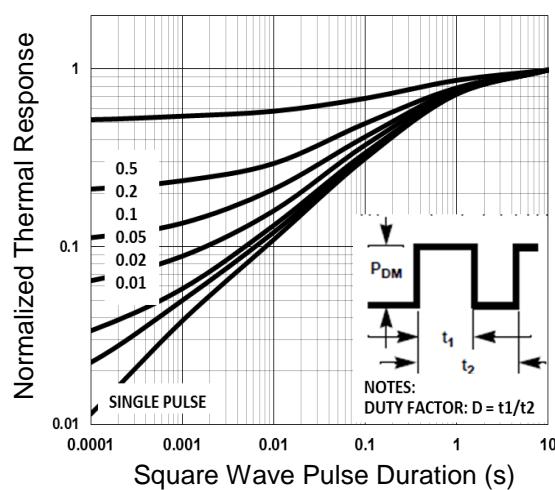
Normalized V_{th} vs. T_j



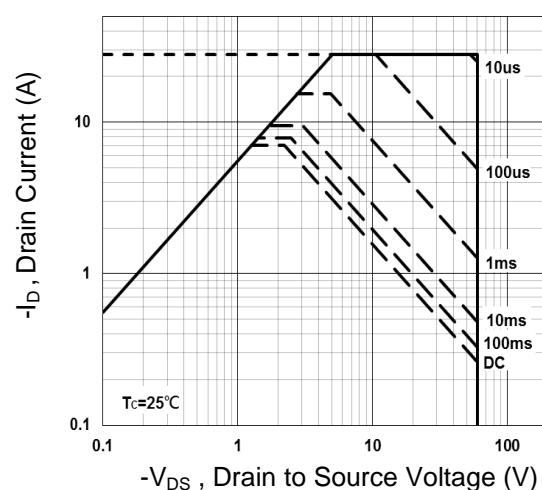
Gate Charge Waveform



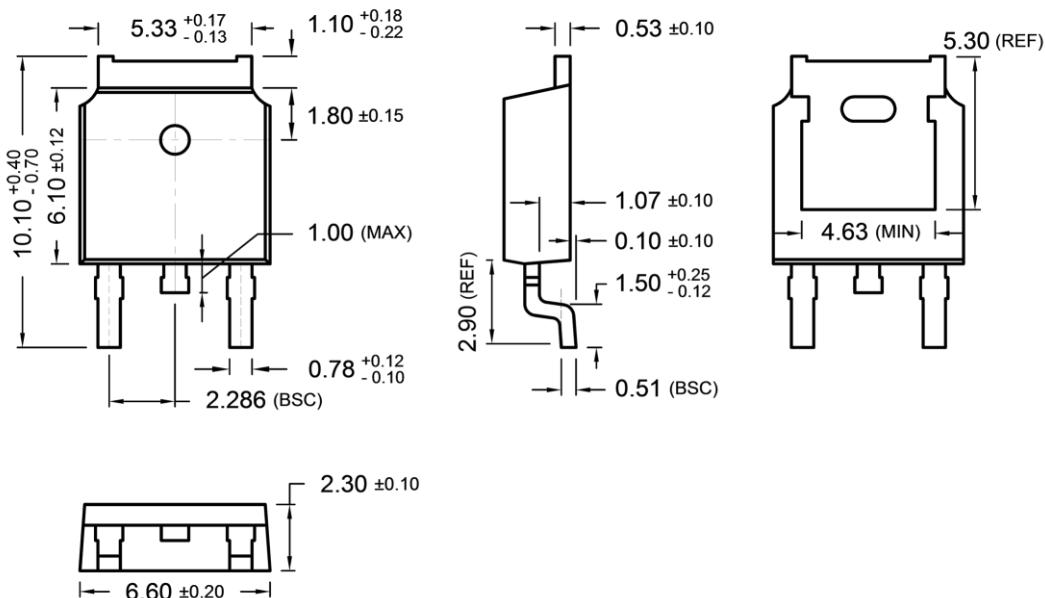
Normalized Transient Impedance



Maximum Safe Operation Area

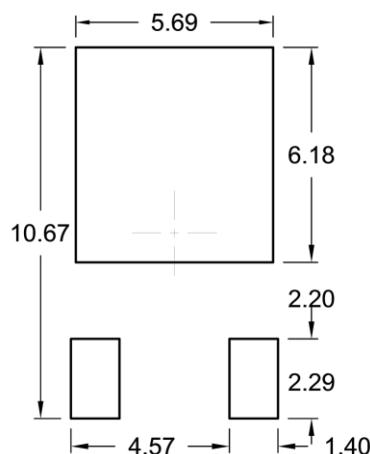


TO-252 Mechanical Drawing

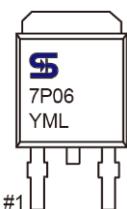


Unit: Millimeters

SUGGESTED PAD LAYOUT (Unit: Millimeters)



Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product

(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep,
X=Oct, **Y**=Nov, **Z**=Dec)

L = Lot Code



RoHS
COMPLIANT

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